



Holey structured graphitic carbon nitride thin sheets with edge oxygen doping via photo-Fenton reaction with enhanced photocatalytic activity

ShuaiNan Guo, Yong Zhu, YunYun Yan, YuLin Min*, JinChen Fan*, QunJie Xu*

Shanghai Key Laboratory of Materials Protection and Advanced Materials in Electric Power, Shanghai University of Electric Power, 200090, China

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ABSTRACT

Holey structured graphitic carbon nitride thin sheets with edge oxygen doping (HS g-C₃N₄-O) via photo-Fenton reaction were reported. The HS g-C₃N₄-O exhibited high surface area of 348 m² g⁻¹ and narrow bandgap (2.434 eV), hence producing high photocatalytic activities for both H₂ generation and Rh.B degradation under solar light irradiation.

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1. Introduction

Photocatalytic hydrogen generation from water using photo-driven reaction has attracted considerable attention as an ideal green technology [1–3]. Of these, a stable photocatalysts which high effectively converts solar energy into chemical fuels is an appreciated alternative. Among various semiconductors photocatalyst, metal-free graphitic carbon nitride (g-C₃N₄) with a suitable band gap and edges has emerged as a new class of photocatalyst due to its nontoxicity, thermal and chemical stability. However, the latest documented quantum yields for H₂ production using pristine g-C₃N₄ does not exceed 4% [4–7], which is far from satisfactory for further application.

As is known, an excellent photocatalyst must possess a high specific surface area to take place redox reactions and a minimizing recombination to take advantage photo-induced charge. Undeniably, the bulk g-C₃N₄ has poor surface area and the high recombination rate. To improve the essential properties of g-C₃N₄, various strategies including heteroatom doping [8–11], layer exfoliation [12], heterojunction configuration [12–15] and carbonaceous scaffold [16–18] have been adopted. Meanwhile, Oxygen

heteroatom has been successfully introduced by a simple H₂O₂ oxidation and its photoactivity has been improved to some extent [19,20]. However, the strongly oxidizing agent of H₂O₂ would be easily break the g-C₃N₄ structure whose is possibly converted into carbon or nitrite oxides. In this sense, rationally controlling the oxidation process would leave behind many vacancies, which could be gradually extended into nanopores texture. The expected oxygen doped g-C₃N₄ with high porosity is able to exhibit impressive photocatalytic activity due to simultaneous doping effect and high active sites.

In this study, a holey structured g-C₃N₄ with edge oxygen doping (HS g-C₃N₄-O) was successfully obtained using photo-Fenton reaction in presence of Fe³⁺/Fe²⁺ and H₂O₂. First, bulk g-C₃N₄ was oxidized and exfoliated into g-C₃N₄ thin sheets with abundant oxygen-containing groups, which based on Niu et al. report [12]. Furthermore, it has also been demonstrated that the photo-Fenton reaction can generate hydroxyl radicals (OH•) under the photoassisted catalysis of Fe³⁺/Fe²⁺ in present of H₂O₂, and which has been considered as one of the most powerful oxidizing species [21]. Thus, the g-C₃N₄ thin sheets with abundant oxygen-containing groups as active defective sites can be partially oxidized and etched, leaving behind carbon vacancies, which gradually extend into nanopores [22,23]. The as-resulted HS g-C₃N₄-O demonstrated a narrow bandgap of 2.434 eV and high surface area of 348 m² g⁻¹, thus presenting highly efficient photocatalytic activity for H₂ generation and Rh.B degradation.

* Corresponding authors.

E-mail addresses: ahaqmylin@126.com (Y. Min), jinchen.fan@gmail.com (J. Fan), xuqunjie@shiep.edu.cn (Q. Xu).

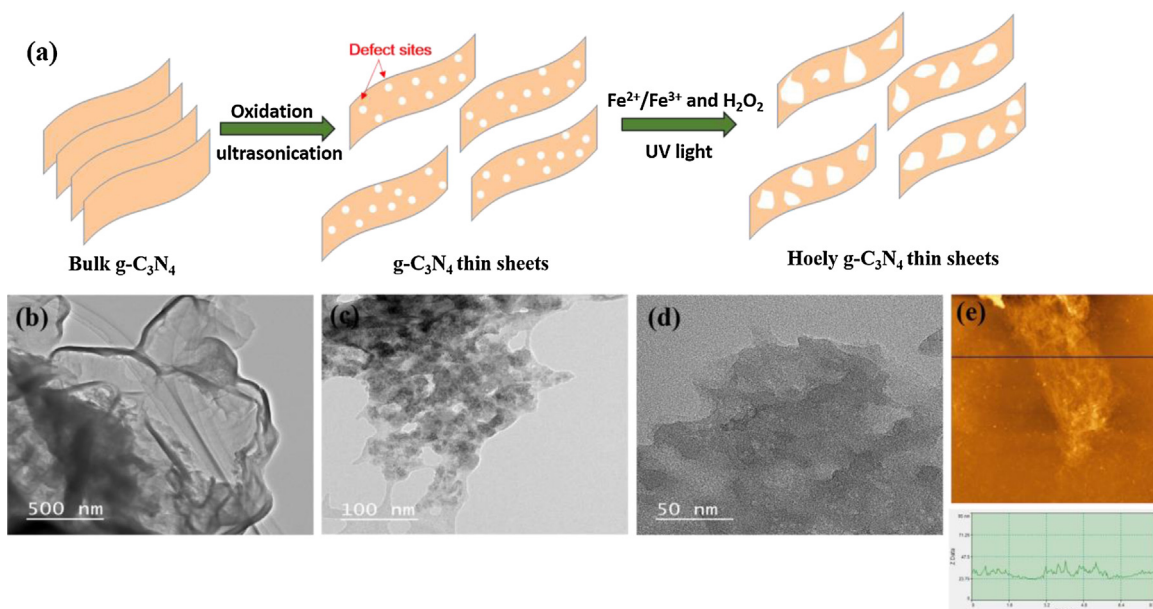


Fig. 1. (a) Schematic illustration of the HS g-C₃N₄-O formation via photo-Fenton reaction. (b) TEM image of oxidized g-C₃N₄ thin sheets. (c and d) TEM image of the HS g-C₃N₄-O. (e) AFM image of the HS g-C₃N₄-O.

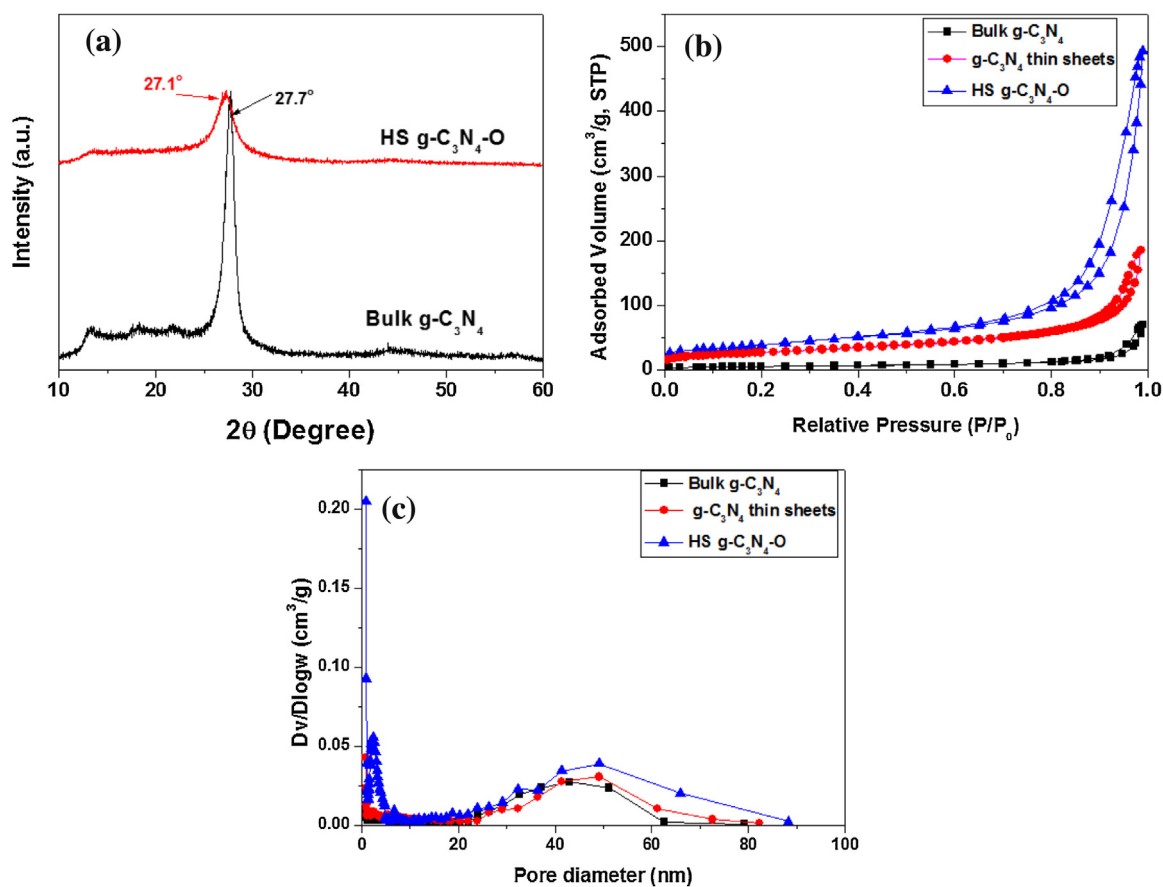


Fig. 2. (a) XRD patterns of the bulk g-C₃N₄ and HS g-C₃N₄-O. (b) Nitrogen adsorption-desorption isotherms and the corresponding pore size distribution curves (c) of the bulk g-C₃N₄, g-C₃N₄ thin sheets and HS g-C₃N₄-O.

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